METHOD OF PREPARING PATTERNED COLLOIDAL CRYSTALS

BACKGROUND OF THE INVENTION

1. Field of the Invention

The present invention pertains, in general, to preparation methods of colloidal crystals used as device materials in optical communication fields, and more specifically, to a method of preparing colloidal crystals for use in manufacturing reflective-mode microdisplays requiring a high efficiency of color display, characterized by forming patterns of photonic crystals including patterns of the crystals with feature size ranged from tens of to hundreds of μm .

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2. Description of the Related Art

Generally, colloidal crystals are structured materials in which uniform polymer or inorganic microspheres are arranged into ordered crystalline structure. As such, the crystalline structure resulting from self-organization is face-centered cubic. When the lattice constant of colloidal crystals is the order of the wavelength of light, light within a specific wavelength cannot penetrate but reflected completely by the colloidal crystals. Thus, since the colloidal crystals affect the transmission of light, they are

referred to as photonic crystals. At present, many efforts have been made to commercialize the photonic crystals. In this regard, bulk shapes of the colloidal crystals should be controlled to manufacture optical devices, such as optical waveguide or lens.

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For patterning of the colloidal photonic crystals, that is, for preparation of patterned photonic crystals in which alternating regions with different photonic band gaps are periodically arranged in the size of tens to hundreds of µm, there is disclosed a method of filling the first particles in microchannels and further filling the second particles each having a different size from that of the first particles between the microchannels (S. M. Yang, H. Miguez, G. A. Ozin, Advanced Functional Materials, 2002, 12, 425). However, this is disadvantageous method in terms of difficulty in repeatedly performing a coating process under complicated conditions. Also, it is impossible to apply the above method to a large area.

In addition, there is proposed a method of patterning a surface and selectively coating particles, by use of a self-assembled monolayer, (Z. -Z. Gu, A. Fujishima, O. Sato, Angew. Chem. Int. Ed. 2002, 41, 2067). But, by the above method, it is difficult to coat multi-layered particles to obtain the desired photonic band gaps. Further, a method of filling the multi-layered particles on previously made patterns is

disclosed (S. M. Yang, G. A. Ozin, Chem. Commun. 2000, 2507), but is disadvantageous in terms of selective filling of the particles.

SUMMARY OF THE INVENTION

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Therefore, it is an aspect of the present invention to alleviate the problems encountered in the related art and to provide a method of preparing finely patterned colloidal crystals having a uniform thickness, by selective polymerization of a polymer.

Another aspect of the present invention is to provide a method of preparing patterned colloidal crystals, by subjecting the finely patterned colloidal crystals to a further selective patterning process.

According to a first embodiment of the present invention to achieve the above aspects, there is provided a method of preparing patterned colloidal crystals, including the steps of filling a monomer solution for photopolymerization at the interstices between the building block spheres of planar colloidal crystals, and performing a selective photopolymerization process inside the colloidal crystals by use of a mask.

According to a second embodiment of the present invention, there is provided a method of preparing patterned

colloidal crystals, including the steps of filling a first solution for photopolymerization inside planar monomer colloidal crystals, performing first a selective photopolymerization process inside the colloidal crystals by use of a mask, and filling a second monomer solution for photopolymerization inside firstly patterned colloidal crystals, followed by further performing at least photopolymerization process inside the firstly patterned colloidal crystals by use of an additional mask.

In the present invention, the feature sizes of the patterns in photonic crystals constituting the patterns can be freely controlled at tens of μm . In addition, a patterning process can be easily performed on a large area, therefore resulting in the preparation of variously patterned photonic crystals useful in industrial fields of displays, optical communications, etc.

Thereby, not only more simplified two-dimensional patterns but also complicated two- or three-dimensional patterns can be obtained.

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BRIEF DESCRIPTION OF THE DRAWINGS

The above and other aspects, features and other advantages of the present invention will be more clearly understood from the following detailed description taken in

conjunction with the accompanying drawings, in which:

FIG. 1 schematically shows a selective photopolymerization process used in the present invention;

FIGS. 2a, 2b and 2c are scanning electron micrographs of patterned colloidal crystals, prepared by use of a monomer solution to be polymerized by absorbing ultraviolet rays;

FIGS. 3a and 3c are scanning electron micrographs of patterned colloidal crystals, and FIG. 3b is an optical micrograph of the patterned colloidal crystals, and FIG. 3d is a photograph showing the thickness of the colloidal crystals in which an inserted image shows a two-dimensional Fourier transform for the crystals; and

FIG. 4 shows a result of a calculation of a dimensionless frequency change of a mid-gap and a photonic band gap (mode 2 and mode 3) in a [111] direction, according to the dielectric contrast of materials filled in the spaces between silica colloidal crystals and particles.

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DETAILED DESCRIPTION OF THE INVENTION

Referring to FIG. 1, there is illustrated a process of forming two-dimensionally patterned crystals by use of a selective photopolymerization device. The device includes planar colloidal crystals 1 formed on a glass substrate, a

mask 2 attached to a lower surface of the glass substrate for two-dimensional patterning, a cover 3 for supporting a photoinitiator-containing monomer solution for use in the photopolymerization by capillary force, and a filter 4 for selecting light of the desired wavelength. In addition, the device is preferably provided with a magnification lens and a displaying portion to observe the polymerization process.

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The planar colloidal crystals 1 are formed according to various methods, for example, a vertical dipcoating method performed on a flat transparent substrate, by use of a suspension containing a polymer and/or inorganic particles with uniform size (P. Jiang, J.F. Bertone, K.S. Hwang, V.L. Colvin, Chem. Mater. 11, 1999, 2132).

The polymer is exemplified by a material capable of being crystallized through self-assembly of a solvent that 15 is evaporated, and is not particularly limited so long as being industrially useful. Usable particles include organic homopolymers, such as polystyrene, polymethyl methacrylate, polyacrylate, polyphenyl methacrylate, polyalphamethylstyrene, poly1-methylcyclohexyl methacrylate, 20 methacrylate, polybenzyl methacrylate, polycyclohexyl methacrylate, poly1-phenylcyclohexyl polychlorobenzyl methacrylate, poly1-phenylethyl methacrylate, polyperfuryl methacrylate, poly1,2-diphenylethyl methacrylate, polypentabromophenyl methacrylate, polydiphenylmethyl 25

methacrylate and polypentachlorophenyl methacrylate; organic such as methylmethacrylate-benzylmethacrylate copolymers, copolymer, styrene-acrylonitrile copolymer, MMA-TFEMA (2,2,2-trifluoroethylmethacrylate) copolymer, MMA-PFPMA (2,2,3,3,3-pentafluoropropylmethacrylate) 5 copolymer, MMA-(1,1,1,3,3,3-hexafluoroisomethacrylate) copolymer, HFIMA (2,2,3,3,4,4,4-heptafluorobutylmethacrylate) MMA-HFBMA copolymer, TFEMA-PFPMA copolymer, TFEMA-HFIMA copolymer, styrene-methylmethacrylate (SM) copolymer, and TFEMA-HFBMA copolymer. 10

Examples of inorganic particle materials include SiO_2 , TiO_2 , ZnS, ZnO_2 , and Fe_3O_4 .

A solvent used for the crystallization by self-assembly is preferably selected from among materials in which particles could be stable by electrostatic or steric repulsion. Such a solvent is exemplified by water, ethanol for electrostatic repulsive particles, toluene, Tetrahydrofuran and polydimenthyl siloxane, and their mixtures for steric repulsive particles.

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The evaporation of the solvent is performed at temperatures lower than a boiling point thereof. As the evaporation rate of the solvent is faster, a time required for forming photonic crystals on the surface of the solvent is shortened. However, an evaporation rate that is too high results in defective crystals. In the present invention,

optimal evaporation conditions for the crystallization depend on the kinds of the particles and solvent used, which may be easily selected by those skilled in the art. The thickness of the planar colloidal crystals is directly proportional to the evaporation rate of the solvent, the concentration of the colloidal solution, and the contact angle between the solvent and the plane, while being inversely proportional to the drawing speed of the plane.

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Although being not particularly limited, the transparent substrate includes glass, polymers, ITO-coated glass, etc.

As shown in FIG. 1, the planar colloidal crystals 1 are covered with a silicone cover 3, and a photoinitiator-containing monomer solution for the polymerization is filled between the crystals 1 and the cover 3.

The monomer suitable for the photopolymerization includes at least one ethylenically-unsaturated double bond, while having various molecular weights, and may undergo addition-polymerization. The 'monomer' includes oligomer, also.

The preferable monomer includes an acrylate monomer, which is exemplified by hydrophilic monomers, such as dimethacryalte, hydroxypropyl methacryalte, hydroxyethyl methacryalte (HEMA), or methacryalte, derived from reactive methacryalte, as well as diglycidyl ether of bisphenol A

(BISGMA).

The above monomer has mono-, di-, or poly-methacrylate (bis-acrylate and bis-methacrylate of polyethylene glycol having a molecular weight of 200-500), such as methyl methacrylate, ethyl methacrylate, isopropyl methacrylate, n-5 hexyl methacrylate, stearyl methacrylate, allyl methacrylate, glycerol dimethacrylate, glycerol trimethacrylate, ethylene glycol dimethacrylate, diethylene glycol dimethacrylate, triethylene glycol dimethacrylate, diethylene qlycol 10 dimethacrylate, triethyleneglycol dimethacrylate, propanediol dimethacrylate, trimethylolpropane trimethacrylate, 1,2,4-butanetriol trimethacrylate, cyclohexanediol diacrylate, pentaerythritol tetramethacrylate, hexamethacrylate, bis-[1-(2-acryloxy)]-psorbitol ethoxyphenyldimethyl methane, bis[1-(3-acryloxy-2-hydroxy)]-15 p-propoxyphenyldimethylmethane, trihydroxyethyl-isocyanurate trimethacrylate, copolymerizable mixtures of acrylated monomers disclosed in US. Patent No. 4,652,274, and acrylated oligomers disclosed in US. Patent 4,642,126, unsaturated amides, such as methylene bis-acrylamide, methylene bis-20 methacrylamide, 1,6-hexamethylene bis-acrylamide, diethylene tris-acrylamide triamine and beta-methacrylaminoethyl methancrylate, and vinyl compounds, such as styrene, diallyl phthalate, divinyl succinate, divinyl adipate and divinyl phthalate. 25

The monomer solution may include one monomer or mixtures of two or more monomers.

The mask 2 suitable for use in the patterning is attached to opposite to the surface of the substrate formed with the colloidal crystals 1, to which light of a desired wavelength is selectively irradiated, thereby causing the photopolymerization only in the particular crystalline regions. As such, unpolymerized regions are removed by being dissolved in an ethanol solvent.

The mask 2 is not particularly limited, and preferably is made by a high-resolution printer having the resolution to the extent of $10\mu m$, for example, Lintronic printer or Linitype-Hell, on a transparent film.

The photoinitiator necessary for the photopolymerization should absorb light between ultraviolet (UV) ranges and visible ranges of 400-700 nm, or infrared ranges of 700-1100 nm.

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As such, the photoinitiator when being used in the visible ranges includes a sensitizer, and an electron donor.

A UV absorbing initiator is exemplified by acetophenone compounds, benzoinether compounds, benzophenone compounds, phosphineoxide compounds, etc., and specifically, carbonyl compounds, such as benzoin, benzoinmethylether, benzoinethylether, benzoinisopropylether, acetoin, butyroin, toluoin, benzyl, benzophenone, p-methoxybenzophenone,

dietoxyacetophenone, α, α -dimethoxy- α -phenylacetophenone, methylphenylglyoxylate, ethylphenylglyoxylate, bis (dimethylaminobenzophenone), and 2-hydroxy-2-methyl-1sulfur phenylpropan-1-one, compounds, such as 1 hydroxycyclohexylphenylketone, tetramethyltiuram monosulfide, and tetramethyltiuram disulfide, azo compounds, such as azobisisobutyronitrile, and azobis-2,4-dimethylvalero, peroxide compounds, such as benzoyl peroxide and di-tertbutyl peroxide.

10 The useful sensitizer should be soluble in the monomer, and absorb light at a suitable wavelength. In addition, preferable sensitizer capable the of is conferring photosensitivity to 2-methyl-4,5-bis(trichloromethyl)-striazine, according to the test procedure disclosed in US. Patent No. 3,729,313. Further, the sensitizer should have 15 shelf stability for necessary times.

The preferable sensitizer includes compounds in the following categories:

Ketones, coumarin dyes (e.g., keto-coumarins), xantene

20 dyes, acridine dyes, thiazole dyes, thiazine dyes, oxazine
dyes, azine dyes, aminoketone dyes, porphyrins, aromatic
polycyclic hydrocarbonds, p-substituted aminostyryl ketone
compounds, aminotriaryl methanes, merocyanines, squarylium
dyes and pyridinium dyes, ketones (e.g., monoketones or

25 alpha-diketones), ketocoumarins, aminoarylketones and p-

substituted aminostyryl ketone compounds. For applications requiring high photosensitivity, it is preferred to employ a sensitizer containing a julolidinyl moiety. For applications requiring a deep cure (e.g., where coated or reinforced fibers weaken similar wavelength of radiation), it is preferred to employ sensitizers having an extinction coefficient below 1000, more preferably below 100, at the desired wavelength of irradiation for the photopolymerization.

For instance, a preferable class of ketone sensitizers 10 has the following Formular:

 $ACO(X)_bB$

Wherein,

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X is CO or CR¹R², R¹ and R² can be the same or different, each represents hydrogen, alkyl, alkaryl, or aralkyl; b is 1 or 0; A and B can be the same or different, substituted (having one or more non-interfering substituents) or unsubstituted aryl, alkyl, alkaryl, or aralkyl, or A and B together can form a cyclic structure, including substituted or unsubstituted alicyclic, aromatic, heteroaromatic or fused aromatic ring.

Ketone compounds suitable for the above Formula include monoketone (b=0), for example, 2,2-, 4,4- or 2,4-dihydroxybenzophenone, di-2-pyriketone, di-2-furanyl ketone, di-2-thiophenyl ketone, benzoin, fluorone, quinone, for example, chloroquinone, 2-aza-3-carboxy-9-fluorone, chalcone,

Michler's ketone, 2-fluoro-9-fluorone, 2-chlorothioxantone, acetophenone, benzophenone, 1- or 2-acetonaphtone, 9 acetylanthracene, 2-, 3- or 9-acetylphenanthrene, 4 acetylbiphenyl, propiophenone, n-butyrophenone, valerophenone, 2-, 3- or 4-acetylpyridine, or 3-acetyl coumarine. Suitable diketone includes aralkyl diketone, such as anthraquinone, penanthrenquinone, o-, m- and p-diacetylbenzene, 1,3-, 1,4-, 1,5-, 1,6-, 1,7- and 1,8-diacetylnaphthalene, 1,5-, 1,8- and 9,10-diacetylanthracene. Suitable α -diketone (b=1, X=CO) includes 2,3-butanedione, 2,3-pentanedione, 2,3-hexanedione, 10 3,4-hexanedione, 2,3-heptanedione, 3,4-heptanedione, 2,3octanedione, 4,5-octanedione, benzyl, 2,2'-, 3,3'- and 4,4'dihydroxybenzyl, furyl, di-3,3'-indolylethanedione, 2,3bornanedione (camphorquinone), 1,2-cyclohexanedione, 1,2naphthaquinone, acenaphthaquinone, etc.

The other preferable sensitizer includes Rose Bengale, fluorescein, Eosin Yellow, Eosin Y, Ethyl Eosin, Eosin Bluish, Erythrosin Yellowish Blend, and 4',5'-dibromofluorescein.

The electron donor may be widely used, and should be soluble in the monomer and have superior shelf stability. The donor functions to increase the speed of the cure or depth of the cure of a composition, when being exposed to light of a desired wavelength. The donor has an oxidation potential that is greater than zero, and is less than or equal to the oxidation potential of p-dimethoxybenzene. The

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oxidation potential is between about 0.5 and 1 versus a saturated calomel electrode (S.C.E.), and may be experimentally measured or obtained from references, such as N.L. Weinburg [Technique of Electroorganic Synthesis Part II Techniques of Chemistry, Vol. V(1975)].

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(including amines includes donor preferable The (including amides aminosilanes), and aminoaldehydes (including thioethers), ureas phosphoramides), ethers (including thioureas), ferrocene, sulfinic acids and thereof, salts of ferrocyanide, ascorbic acid and salts thereof, dithiocarbamic acid and salts thereof, salts of xantate, salts of ethylene diamine tetraacetic acid and salts of tetraphenylboronic acid. The donor may be unsubstituted or substituted with one or more non-interfering substituents. In particular, the preferable donor includes an electron donor atom, such as nitrogen, oxygen, phosphor or sulfur, and an abstractable hydrogen atom bonded to a carbon or silicon atom alpha to the electron donor atom.

The preferable amine donor includes alkyl-, aryl-, alkaryl- and aralkyl-amines, such as methylamine, ethylamine, amylamine, butylamine, triethanolamine, propylamine, hexylamine, 2,4-dimethylaniline, 2,3-dimethylaniline, o-, maminopyridine, N, N'benzylamine, p-toluidine, and N, N'-N,N'-diethylethylenediamine, dimethylethylenediamine, N,N'-diethyl-1,3-propanediamine, dibenzylethylenediamine,

N, N'-diethyl-2-butene-1, 4-diamine, N, N'-dimethyl-1, 6piperazine, 4,4'-trimethylenedipiperidine, hexanediamine, 4,4'-ethylenedipiperidine, p-N,N-dimethylaminopentanol and p-N-dimethylaminobenzonitrile; aminoaldehydes, such as p-N,Ndimethylaminobenzaldehyde, p-N,N-diethylaminobenzaldehyde, 9julolidinecarboxaldehyde and 4-morpholinobenzaldehyde; such trimethylsilylmorpholine, aminosilanes, as trimethylsilylpiperidine, bis(dimethylamino)diphenylsilane, tris(dimethylamino)methylsilane, N, N-diethylamino tris(dimethylamino)phenylsilane, trimethylsilane, 10 tris(dimethylsilyl)amine, tris(methylsilyl)amine, bis (dimethylsilyl) amine, N, N-bis (dimethylsilyl) aniline, N, N-dimethyl-Nphenyl-N-dimethylsilylaniline and dimethylsilylamine. Tertiary aromatic alkylamines, particular, those having one or more electron-withdrawing 15 groups on the aromatic ring, have been found to provide superior shelf stability, which can result from the use of amines that are solid at room temperature.

The preferable amide donor compounds include N,N-dimethylacetamide, N,N-diethylacetamide, N-methyl-N-phenylacetamide, hexamethylphosphoramide, hexapropylphosphoramide, trimorpholinophosphine oxide and tripiperidinophosphine oxide.

The preferable ether donor compounds include 4,4'-dimethoxybiphenyl, 1,2,4-trimethoxybenzene and 1,2,4,5-

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tetramethoxybenzene.

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The preferable urea donor compounds include N,N'-dimethylurea, N,N-dimethylurea, N',N'-diphenylurea, tetramethylthiourea, tetraethylthiourea, tetra-n-butylthiourea, N,N-di-n-butylthiourea, N,N'-di-n-butylthiourea, N,N-diphenylthiourea and N,N'-diphenyl-N,N'-diethylthiourea.

In the present invention, a photoinitiator system for use in the photopolymerization includes a ternary system disclosed in US. Patent No. 5,545,676. In such a ternary system, a third component is diaryliodonium or sulfonium salt, in addition to the sensitizer and the electron donor as first and second components, respectively. The above salt should be soluble in the monomer, and preferably is shelf-stable when dissolved therein in the presence of the sensitizer and electron donor. Thus, selection of a particular iodonium or sulfonium salt may depend to some extent on the particular monomer, sensitizer and donor chosen. The ternary system should include the three components, but further include one or more sensitizers or electron donors if desired.

Useful salts are disclosed in US. Patent Nos. 3,729,313, 3,741,769, 3,808,006, 4,250,053 and 4,394,403.

The preferable iodonium salt includes diphenyliodonium chloride, diphenyliodonium hexafluorophosphate and diphenyliodonium tetrafluoroborate.

The useful sulfonium complex salt is substituted with one or more aromatic groups, and preferably, three aromatic groups. A representative group is an aromatic group having 4-20 carbons, and selected from among phenyl, thienyl and furanyl group. These aromatic groups may have selectively one or more fused benzo groups (e.g., naphthyl, etc.; benzothienyl, dibenzothienyl; benzofuranyl, dibenzofuranyl, etc.). Such aromatic groups may be substituted by at least one group, below, or other groups essentially unreactive with other components present on a specific composition in which the complex salt is used: halogen, nitro, aryl, ester, sulfoester, amido, carbamyl, sulfamyl, alkoxy, aryl, alkyl, aryloxy, alkylsulfonyl, arylsulfonyl, perfluoroalkyl and perfluoroalkylsulfonyl.

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preferable aromatic sulfonium complex salt The includes triphenylsulfonium tetrafluoroborate, tetrafluoroborate, methyldiphenylsulfonium hexafluorophosphate, dimethylphenylsulfonium triphenylsulfonium triphenylsulfonium hexafluorophosphate, 4-butoxyphenyldiphenylsulfonium hexafluoroantimonate, 4-chlorophenyldiphenylsulfonium tetrafluoroborate, tris (4-phenoxyphenyl) sulfonium hexafluoroantimonate, hexafluorophosphate, di (4-ethoxyphenyl) methylsulfonium 4-acetamidophenyldiphenylsulfonium hexafluoroarcenate, dimethylnaphthylsulfonium tetrafluoroborate,

trifluoromethyldiphenylsulfonium hexafluorophosphate, tetrafluoroborate, methyl (N-methylphenothiazinyl) sulfonium hexafluoroantimonate, phenylmethylbenzylsulfonium hexafluorophosphate, 10-methylphenoxantinium hexafluorophosphate, 5-methylthianthrenium hexafluorophosphate, 10-phenyl-9,9-dimethylthioxanthenium hexafluorophosphate, 10-phenyl-9-oxothioxanthenium and 5-methyl-10,10-dioxothianthrenium tetrafluoroborate, hexafluorophosphate.

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The preferable salt is triaryl-substituted salts, such as triphenylsulfonium hexafluorophosphate. The triaryl-substituted salts are higher in thermal stability than that of mono- and di-aryl-substituted salts, and thus may be applied to a curable system requiring a long storage life. The triaryl-substituted complex salt is more suitable for photosensitizing the dye used in the present invention.

To perform the polymerization of the polymer filled between the colloidal crystals, a material inducing the polymerization by absorbing light near the infrared rays or visible light of a high wavelength is used, which is favorable in terms of the formation of fine patterns. FIGS. 2a, 2b and 2c show electron micrographs (215, 750 and 6879 magnifications) of patterned colloidal crystals polymerized by absorbing UV rays of 200-300 nm. FIGS. 3a and 3c show electron micrographs of patterned colloidal crystals

polymerized by absorbing visible light of 400-600 nm, and FIG. 3b shows an optical micrograph of the above patterned colloidal crystals. From this, it can be found that crystals polymerized by absorbing light near the infrared rays or visible light of a high wavelength can be more finely patterned.

Having generally described this invention, a further understanding can be obtained by reference to certain specific examples which are provided herein for purposes of illustration only and are not intended to be limiting unless otherwise specified. Accordingly, the photopolymerization materials having optimal conditions required for obtaining desired pattern sizes or refractive index of polymers may be freely selected by those skilled in the art.

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EXAMPLE 1

Preparation of $100\mu m \times 100\mu m$ Square Patterned Colloidal Crystals

A mask having $100\mu m \times 100\mu m$ square patterns was used. As planar colloidal crystals, a glass substrate on which an organic material was completely removed by a Piranha solution of sulfuric acid and hydrogen peroxide was dipped into an aqueous solution having 1 wt% of 230 nm sized silica particles, and then drawn at a rate of $0.02\mu m/sec$, to form a

crystalline structure comprising ten-layered silica particles. Both ends of the glass substrate were wound by a 60µm thick polyimide tape as a spacer so as not to bring crosslinked (or cured) PDMS (PolyDiMethylSiloxane) rubber into direct contact with the colloidal crystals.

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Then, a monomer solution for the photopolymerization filled between the glass substrate having colloidal crystals and a cover of crosslinked PDMS rubber. As such, the monomer solution was composed of 0.1 wt% of 4-7-diiodoinducing fluorine dye the 3-butoxy-6-fluorone as a photopolymerization by absorbing light of 400-600nm to transfer energy of the absorbed light to an photoinitiator, 5 wt% of amine acrylate initiating the polymerization by donating an electron to form a radical, 0.15 wt% of (4octyloxyphenyl)phenyldiphenyliodonium hexafluoroantimonate (OPPI) serving to prevent the bleaching of the dye and to aid the photopolymerization, and 94.75 wt% of alkoxylated trifunctional acrylate ester as a monomer.

On a microscope equipped with a mercury lamp and a fluorescent filter, a preparative sample was placed, after which the size and position of a focal point of the microscope were set to a region of the sample to be polymerized, by use of an optical filter acting to pass light of 400-600 nm therethrough. Then, light required for the polymerization was irradiated (30 sec - 1 min), to

complete the polymerization. Thereafter, the PDMS cover was removed and an unpolymerized region was dissolved in ethanol, and removed.

FIG. 4 shows the calculated dimensionless frequency change of a mid-gap and a photonic band gap (frequency area between mode 2 and mode 3) in a [111] direction, according to the dielectric contrast of materials filled in the spaces between the colloidal crystals and the particles. As shown in FIG. 4, in cases where the polymer materials are filled between the interstices of particles, a variety of refractive indexes can result. As such, variable positions of the photonic band gaps may be theoretically expected.

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As described above, the present invention provides a method of preparing patterned colloidal crystals, characterized in that colloidal crystalline regions oriented in the same direction with different refractive indexes can be controlled in the level of μm , and repeated patterns can be inexpensively and easily prepared. To further control the refractive index, patterns in the level of μm may be additionally formed at an unpolymerized region through other organic polymerizations or inorganic reactions.

The inventive method is advantageous in terms of the controllable optical properties of the colloidal crystals, for example, photonic band gaps, whereby end products can be

used for panels having high reflectibility of reflective microdisplays.

The present invention has been described in an illustrative manner, and it is to be understood that the terminology used is intended to be in the nature of description rather than of limitation. Many modifications and variations of the present invention are possible in light of the above teachings. Therefore, it is to be understood that within the scope of the appended claims, the invention may be practiced otherwise than as specifically described.

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